BSM120D12P2C005 Information

For Reference Only	**Part Number** BSM120D12P2C005	
	Manufacturer Rohm Semiconductor	
	Category Discrete Semiconductor Products Transistors - FETs, MOSFETs - Arrays	
	Description MOSFET 2N-CH 1200V 120A MODULE	
	Package Module	
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.

BSM120D12P2C005 Specifications

Manufacturer Part Number	BSM120D12P2C005
Manufacturer	Rohm Semiconductor
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Arrays
Package	Module
Series	-
FET Type	2 N-Channel (Half Bridge)
FET Feature	Standard
Drain to Source Voltage (Vdss)	1200V (1.2kV)
Current - Continuous Drain (Id) @ 25°C	120A
Rds On (Max) @ Id, Vgs	-
Vgs(th) (Max) @ Id	2.7V @ 22mA
Gate Charge (Qg) (Max) @ Vgs	-
Input Capacitance (Ciss) (Max) @ Vds	14000pF @ 10V
Power - Max	780W
Operating Temperature	-40°C ~ 150°C (TJ)
Mounting Type	-
Package / Case	Module
Supplier Device Package	Module
	Report errors?

BSM120D12P2C005 Guarantees

Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

BSM120D12P2C005 Payment Methods

BSM120D12P2C005 Shipping Methods

If you have any question about BSM120D12P2C005, please do not hesitate to contact us!

Website: https://www.heisener.com

E-mail: salesdept@heisener.com